

#### **FEATURES**

- Precision Current Control
- ±800mA Load Current
- 1.25V Total VSAT at 800mA
- Controlled Velocity Head Parking
- Precision Dual Supply Monitor with Indicator
- Limit Input to Force Output Extremes
- Inhibit Input and UVLO
- 4V to 15V operation

#### DESCRIPTION

This full-bridge power amplifier is rated for continuous output current of 0.8 Amperes and is intended for use in demanding servo applications such as head positioning for high-density disk drives. The device includes a precision current sense amplifier that provides accurate control of load current. Current is sensed with a single resistor in series with the load. The power amplifier has a very low output saturation voltage and will operate down to 4V supply levels. Power output stage protection includes current limiting and thermal shutdown.

Auxiliary functions on this device include a dual-input under-voltage comparator, which can monitor two independent supply voltages and force a built-in head park function when either is below minimum. When activated by either the UV comparator, or a command at the separate PARK input, the park circuitry will override the amplifier inputs to convert the power outputs to a programmable constant voltage source which will hold regulation as the supply voltage falls to below 3.0 Volts. Added features include a POWER OK flag output, a LIMIT input to force the drive output to its maximum level in either polarity, and a over-riding INHIBIT input to disable all amplifiers and reduce quiescent supply current.

This device is packaged in a power PLCC surface mount configuration which maintains a standard 28-pin outline, but with 7 pins along one edge allocated to ground for optimum thermal transfer. And is also available in a 24-pin surface mount SOIC package.



#### BLOCK DIAGRAM

#### UC3175B

#### ABSOLUTE MAXIMUM RATINGS

Note 1: Unless otherwise indicated, voltages are referenced to ground and currents are positive into, negative out of, the specified terminals. "Pulsed" is defined as a less than 10% duty cycle pulse with a maximum duration of 500µs. Note 2: See Unitrode Integrated Circuits databook for information regarding thermal specifications and limitations of packages.

## Thermal Data QP Package:

Thermal Resistance Junction to Leads,
θJL
Thermal Resistance Junction to Ambient,
θja

#### **CONNECTION DIAGRAMS**

		PLCC-28 (Top View)	PACKAGE PIN FUNCTIO	PACKAGE PIN FUNCTION		
DW Package		QP Package	FUNCTION	PIN		
		C	+VIN	1		
			INH	2		
+VIN 1	24 C/S Out		UV2	3		
	Bark Drive		UV1	4		
	23 Faik Dilve		Limit	5		
UV2 3	22 Park	4 3 2 1 28 27 26	Park Volts	6		
	21 Pwr OK	5 25	C/S-	7		
			A+/REF Input	8		
Limit 5	20 C/S+		A- In	9		
Park Volts 6	19 B+ In		A Output	10		
0/8 7	10 D in	8 22	A Cur Sen	11		
		9 21	Gnd (Heat Dissipation Pins)	12-18		
A+/REF Input 8	17 +Vc Supply	10 20	B Cur Sen	19		
A- In 9	16 B Output		B Output	20		
	<b>G</b>	12 13 14 15 16 17 18	+Vc Supply	21		
A Output 10	15 B Output		B- In	22		
A Output 11	14 B Cur Sen		B+ In	23		
A Cur Sen 12	12 Gnd		C/S+	24		
			Pwr OK	25		
			Park	26		
			Park Drive	27		
			C/S Out	28		

### **ELECTRICAL CHARACTERISTICS:** Unless otherwise stated specifications apply for 0°C ≤ TA ≤ 70°C, +VIN = 12V, +VC

= +VIN, A+/REF Input = 6V. TA=TJ. MAX UNITS PARAMETER **TEST CONDITIONS** MIN ТҮР **INPUT SUPPLY** All Amplifier Outputs = 6V +VIN Supply Current 35 42 mΑ +Vc Supply Current IOUT = 0A 1 mΑ +VIN UVLO Threshold Low to High 2.8 3.0 V UVLO Threshold Hysteresis 200 mV

 $\label{eq:characteristics} \begin{array}{l} \textbf{ELECTRICAL} \\ \textbf{CHARACTERISTICS (cont.)} \end{array} \quad Unless otherwise stated specifications apply for 0°C \leq TA \leq 70°C, +VIN = 12V, +VC = +VIN, \\ A+/REF INPUT = 6V. TA=TJ. \end{array}$ 

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
UNDER VOLTAGE (UV) COMPARATOR			1	1	<u> </u>
Input Bias Current		-1.5	-0.5		μA
UV Thresholds	Low to High, Other Input = 5V	1.48	1.50	1.52	V
UV Threshold Hysteresis		15	25	40	mV
Pwr OK Vsat	IOUT = 5mA			0.45	V
Pwr OK Leakage	Vout = 20V			5	μA
POWER AMPLIFIERS A and B				I	1 .
Input Offset Voltage	VCM = 6V, A Amplifier			8	mV
	B Amplifier			12	mV
Input Offset Drift	Note 1, A Amplifier Only			25	μV/°C
Input Bias Current	VCM = 6V, except A+/REF Input	-500	-150		nA
Input Offset Current	VCM = 6V, B Amplifier Only			200	nA
Input Bias Current at A+/Ref Input	(A+/Ref–C/S+)/12k, TJ = 25°C	60	84	105	μA/V
CMRR	$1V \leq VCM \leq 10V$	70	90		dB
PSRR	+VIN = 4V to 15V, VCM = 1.5V	70	90		dB
Large Signal Voltage Gain	VOUT = 1V. Sinking 500mA to VOUT = 11V.				
	Sourcing 500mA	3.0	15.0		V/mV
Slew Rate	1 to 13V. 13 to 1V. TJ = 25°C		1	2.1	V/us
Unity Gain Bandwidth	Note 1. A Amplifier		2		MHz
	Note 1. B Amplifier		1		MHz
High-Side Current Limit		0.8	1.0		Α
Output Saturation Voltage	High-Side, ISOURCE = 250mA		0.7		V
	High-Side, ISOURCE = 800mA		0.85		V
	Low-Side. ISINK = 250mA		0.3		V
	Low-Side, ISINK = 800mA		0.4		V
	Total. IOUT = 250mA		1.0	1.2	V
	Total, IOUT = 800mA		1.25	1.6	V
High Side Diode VF	ID = 800mA. Inhibit Activated		1.0		V
Low Side Diode VF	$I_D = 800 \text{mA}$ . Inhibit Activated		1.0		V
CURRENT SENSE AMPLIFIER					<u> </u>
Input Offset Voltage	$V_{CM} = 6V$			2.0	mV
Input Offset Change with Common Mode	$0V \le V_{CM} \le 12V$				
Input				1500	цV/V
Input Offset Drift	Note 1			8	µV/°С
Voltage Gain	$-1.0V \le VDIFE \le +1.0V$ VCM = 6V	1.95	2 00	2 05	V
Output Saturation Voltage	1  ow-Side Isink = 1.5mA	1.00	0.3	0.5	V
Ouput Galdration Voltage	High-Side Isource = $1.5mA$	-	0.0	0.0	V
Maximum A+/Ref Input	Volts Below +VIN_C/S+ & C/S- = BOUTPUT Max @		0.1	0.7	-
	10mA Output Current $+V_{IN} = 4.5V_{C}/S_{VIO} < 5mV$		26	3.0	v
PARKING FUNCTION			2.0	0.0	Y
Park Input Threshold		07	1 1	17	V
Park Input Current	Park Input = 1 7V	0.1	60	100	ν 11 Δ
Park Drive Saturation Voltage PDVsAT	$I_{\text{SINK}} = 100 \text{mA}$		0.3	0.5	V
Parking Drive Leakage			0.0	100	
Amplifier A Aux Input Rias Current	V001 - 20V	-500	-150	100	n A
Ampline A Aux input bias outlent		-500	-100	1	

# ELECTRICAL Unless otherwise stated specifications apply for 0°C ≤ TA ≤ 70°C, +VIN = 12V, +Vc = +VIN, CHARACTERISTICS (cont.) A+/REF Input = 6V. TA=TJ. PARAMETER TEST CONDITIONS MIN TYP MAX UNITS

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
PARKING FUNCTIONS (cont.)					
Amplifier A Saturation Voltage, AHVSAT	ISOURCE = 50mA, +VIN = 3V		0.65	0.8	V
Regulating Voltage at Park Volts		1.47	1.50	1.53	V
Minimum Parking Supply Voltage	AHVSAT + PDVSAT ≤ 1.3V @ 50mA		1.7	1.9	V
AUXILIARY FUNCTIONS					
Limit Input Low Voltage	A Output Forced Low	0.7	0.8		V
Limit Input High Voltage	A Output Forced High		2.2	2.3	V
Limit Inactive		1.2		1.8	V
Limit Open Circuit Voltage		1.45	1.50	1.55	V
Limit Input Resistance	1.2V ≤ Limit Input ≤ 1.8V		10		kΩ
Inhibit Input Threshold		0.7	1.1	1.7	V
Inhibit Input Current	Inhibit Input = 1.7V		400	700	μA
Supply Current when Inhibited	The sum of +VIN and +Vc currents		2	6	mA
Thermal Shutdown Temperature			165		°C

Note 1: This specification not tested in production.

#### UC3175B Series Current Sensing



#### **Parking Function**



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